

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	3	semiconductor adj device and surface near2 "mm.sup.2" and ratio and H and L and length and distance and substrate	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/19 16:28
L3	3	semiconductor adj device and surface near2 "mm.sup.2" and ratio and length and distance and substrate and thermal adj conductivity	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/19 16:26
L4	1	(semiconductor adj device and surface and "mm.sup.2" and ratio and length and distance and substrate and thermal and conductivity).clm.	US-PGPUB	OR	OFF	2007/09/19 16:29